



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

the Application of: **HAYASHI, et al.**

Group Art Unit: 2813

Serial No.: **09/955,600**

Examiner: Tuan H. Nguyen

Filed: **September 19, 2001**

Confirmation No.: **1668**

For: **SEMICONDUCTOR DEVICE AND METHOD OF FABRICATING
THE SAME AND METHOD OF FORMING NITRIDE BASED
SEMICONDUCTOR LAYER**

Attorney Docket Number: **990852A**
Customer Number: **38834**

AMENDMENT AFTER FINAL REJECTION

BOX: AF

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

September 3, 2004

Sir:

In response to the Office Action dated March 5, 2004, please amend the above-identified application as follows:

Amendment to the Claims begins on page 2 of this paper.

Remarks begin on page 4 of this paper.